

## Freeform Search

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<b>Database:</b>	<input type="checkbox"/> US Pre-Grant Publication Full-Text Database <input type="checkbox"/> US Patents Full-Text Database <input type="checkbox"/> US OCR Full-Text Database <input type="checkbox"/> EPO Abstracts Database <input type="checkbox"/> JPO Abstracts Database <input type="checkbox"/> Derwent World Patents Index <input type="checkbox"/> IBM Technical Disclosure Bulletins
<b>Term:</b>	<input type="text" value="L9 and l7"/> <span style="float: right;"><input type="checkbox"/></span>
<b>Display:</b>	<input type="text" value="50"/> Documents in <b>Display Format:</b> [-] Starting with Number <input type="text" value="1"/>
<b>Generate:</b> <input type="radio"/> Hit List <input checked="" type="radio"/> Hit Count <input type="radio"/> Side by Side <input type="radio"/> Image	

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### Search History

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**DATE:** Friday, September 10, 2004 [Printable Copy](#) [Create Case](#)

<u>Set</u> <u>Name</u> <u>Query</u>	<u>Hit</u> <u>Count</u>	<u>Set</u> <u>Name</u>
side by side		result set
<i>DB=PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD; PLUR=YES; OP=OR</i>		
<u>L11</u> L9 and l7	41	<u>L11</u>
<u>L10</u> L9 and l7	41	<u>L10</u>
<u>L9</u> l1 and threshold\$3 and voltag\$1 and (mos with transistor\$1) and modulat\$3 and (resistor\$1 or resistance or resistive)	998	<u>L9</u>
<u>L8</u> L7 and l6	0	<u>L8</u>
<u>L7</u> 326/\$.ccls.	21989	<u>L7</u>
<u>L6</u> L5 and modulat\$3	68	<u>L6</u>
<u>L5</u> L4 and resistor\$1	438	<u>L5</u>
<u>L4</u> L2 and (mos with transistor\$1)	646	<u>L4</u>
<u>L3</u> L2 and (mos with transistor\$1)	1	<u>L3</u>
<u>L2</u> L1 with threshold\$3 with voltag\$1	2534	<u>L2</u>
<u>L1</u> current adj sourc\$3	159339	<u>L1</u>

END OF SEARCH HISTORY